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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Obsolete
Core Processor	RL78
Core Size	16-Bit
Speed	32MHz
Connectivity	CSI, I <sup>2</sup> C, LINbus, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	34
Program Memory Size	192KB (192K x 8)
Program Memory Type	FLASH
EEPROM Size	8K x 8
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	1.6V ~ 5.5V
Data Converters	A/D 10x8/10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	48-LQFP
Supplier Device Package	48-LFQFP (7x7)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f100ghdfb-v0">https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f100ghdfb-v0</a>

Table 1-1. List of Ordering Part Numbers

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Pin count	Package	Data flash	Fields of Application Note	Ordering Part Number
48 pins	48-pin plastic HWQFN (7 × 7 mm, 0.5 mm pitch)	Mounted	A	R5F100GAANA#U0, R5F100GCANA#U0, R5F100GDANA#U0, R5F100GEANA#U0, R5F100GFANA#U0, R5F100GGANA#U0, R5F100GHANA#U0, R5F100GJANA#U0, R5F100GKANA#U0, R5F100GLANA#U0 R5F100GAANA#W0, R5F100GCANA#W0, R5F100GDANA#W0, R5F100GEANA#W0, R5F100GFANA#W0, R5F100GGANA#W0, R5F100GHANA#W0, R5F100GJANA#W0, R5F100GKANA#W0, R5F100GLANA#W0
		Not mounted	D	R5F100GADNA#U0, R5F100GCDNA#U0, R5F100GDDNA#U0, R5F100GEDNA#U0, R5F100GFDNA#U0, R5F100GGDNA#U0, R5F100GHDNA#U0, R5F100GJDNA#U0, R5F100GKDNA#U0, R5F100GLDNA#U0 R5F100GADNA#W0, R5F100GCDNA#W0, R5F100GDDNA#W0, R5F100GEDNA#W0, R5F100GFDNA#W0, R5F100GGDNA#W0, R5F100GHDNA#W0, R5F100GJDNA#W0, R5F100GKDNA#W0, R5F100GLDNA#W0
			G	R5F100GAGNA#U0, R5F100GCGNA#U0, R5F100GDGNA#U0, R5F100GEGNA#U0, R5F100GFGNA#U0, R5F100GGGNA#U0, R5F100GHGNA#U0, R5F100GJGNA#U0 R5F100GAGNA#W0, R5F100GCGNA#W0, R5F100GDGNA#W0, R5F100GEGNA#W0, R5F100GFGNA#W0, R5F100GGGNA#W0, R5F100GHGNA#W0, R5F100GJGNA#W0
48 pins	48-pin plastic HWQFN (7 × 7 mm, 0.5 mm pitch)	Mounted	A	R5F101GAANA#U0, R5F101GCANA#U0, R5F101GDANA#U0, R5F101GEANA#U0, R5F101GFANA#U0, R5F101GGANA#U0, R5F101GHANA#U0, R5F101GJANA#U0, R5F101GKANA#U0, R5F101GLANA#U0 R5F101GAANA#W0, R5F101GCANA#W0, R5F101GDANA#W0, R5F101GEANA#W0, R5F101GFANA#W0, R5F101GGANA#W0, R5F101GHANA#W0, R5F101GJANA#W0, R5F101GKANA#W0, R5F101GLANA#W0
		Not mounted	D	R5F101GADNA#U0, R5F101GCDNA#U0, R5F101GDDNA#U0, R5F101GEDNA#U0, R5F101GFDNA#U0, R5F101GGDNA#U0, R5F101GHDNA#U0, R5F101GJDNA#U0, R5F101GKDNA#U0, R5F101GLDNA#U0 R5F101GADNA#W0, R5F101GCDNA#W0, R5F101GDDNA#W0, R5F101GEDNA#W0, R5F101GFDNA#W0, R5F101GGDNA#W0, R5F101GHDNA#W0, R5F101GJDNA#W0, R5F101GKDNA#W0, R5F101GLDNA#W0
			G	R5F101GAGNA#U0, R5F101GCGNA#U0, R5F101GDGNA#U0, R5F101GEGNA#U0, R5F101GFGNA#U0, R5F101GGGNA#U0, R5F101GHGNA#U0, R5F101GJGNA#U0 R5F101GAGNA#W0, R5F101GCGNA#W0, R5F101GDGNA#W0, R5F101GEGNA#W0, R5F101GFGNA#W0, R5F101GGGNA#W0, R5F101GHGNA#W0, R5F101GJGNA#W0

**Note** For the fields of application, refer to **Figure 1-1 Part Number, Memory Size, and Package of RL78/G13**.

**Caution** The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

### Table 1-1. List of Ordering Part Numbers

(7/12)

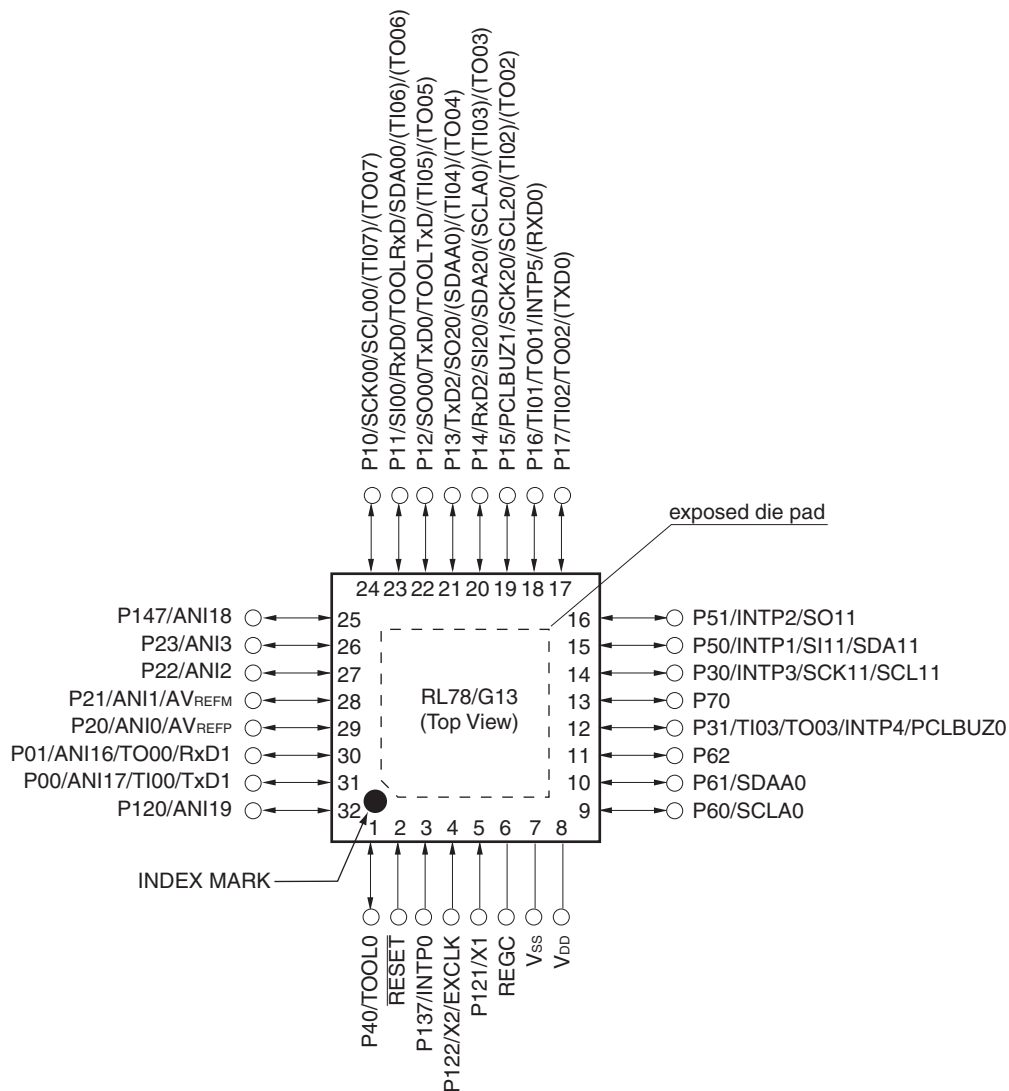
Pin count	Package	Data flash	Fields of Application <small>Note</small>	Ordering Part Number
52 pins	52-pin plastic LQFP (10 × 10 mm, 0.65 mm pitch)	Mounted	<p>A</p> <p>D</p> <p>G</p>	<p>R5F100JCAFA#V0, R5F100JDAFA#V0, R5F100JEAFA#V0, R5F100JFAFA#V0, R5F100JGAFA#V0, R5F100JHAFA#V0, R5F100JJAFA#V0, R5F100JKAFa#V0, R5F100JLAFA#V0</p> <p>R5F100JCAFA#X0, R5F100JDAFA#X0, R5F100JEAFA#X0, R5F100JFAFA#X0, R5F100JGAFA#X0, R5F100JHAFA#X0, R5F100JJAFA#X0, R5F100JKAFa#X0, R5F100JLAFA#X0</p> <p>R5F100JCDAFA#V0, R5F100JDDFA#V0, R5F100JEDFA#V0, R5F100JFDAFA#V0, R5F100JGDFA#V0, R5F100JHDAFA#V0, R5F100JJDFA#V0, R5F100JKDAFA#V0, R5F100JLDAFA#V0</p> <p>R5F100JCDAFA#X0, R5F100JDDFA#X0, R5F100JEDFA#X0, R5F100JFDAFA#X0, R5F100JGDFA#X0, R5F100JHDAFA#X0, R5F100JJDFA#X0, R5F100JKDAFA#X0, R5F100JLDAFA#X0</p> <p>R5F100JCGFA#V0, R5F100JDGFA#V0, R5F100JEGFA#V0, R5F100JFGFA#V0, R5F100JGGFA#V0, R5F100JHGFA#V0, R5F100JJGFA#V0</p> <p>R5F100JCGFA#X0, R5F100JDGFA#X0, R5F100JEGFA#X0, R5F100JFGFA#X0, R5F100JGGFA#X0, R5F100JHGFA#X0, R5F100JJGFA#X0</p>
		Not mounted	<p>A</p> <p>D</p>	<p>R5F101JCAFA#V0, R5F101JDAFA#V0, R5F101JEAFA#V0, R5F101JFAFA#V0, R5F101JGAFA#V0, R5F101JHAFA#V0, R5F101JJAFA#V0, R5F101JKAFa#V0, R5F101JLAFA#V0</p> <p>R5F101JCAFA#X0, R5F101JDAFA#X0, R5F101JEAFA#X0, R5F101JFAFA#X0, R5F101JGAFA#X0, R5F101JHAFA#X0, R5F101JJAFA#X0, R5F101JKAFa#X0, R5F101JLAFA#X0</p> <p>R5F101JCDAFA#V0, R5F101JDDFA#V0, R5F101JEDFA#V0, R5F101JFDAFA#V0, R5F101JGDFA#V0, R5F101JHDAFA#V0, R5F101JJDFA#V0, R5F101JKDAFA#V0, R5F101JLDAFA#V0</p> <p>R5F101JCDAFA#X0, R5F101JDDFA#X0, R5F101JEDFA#X0, R5F101JFDAFA#X0, R5F101JGDFA#X0, R5F101JHDAFA#X0, R5F101JJDFA#X0, R5F101JKDAFA#X0, R5F101JLDAFA#X0</p>

**Note** For the fields of application, refer to **Figure 1-1 Part Number, Memory Size, and Package of RL78/G13**.

**Caution** The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

### 1.3.5 32-pin products

- 32-pin plastic HWQFN (5 × 5 mm, 0.5 mm pitch)

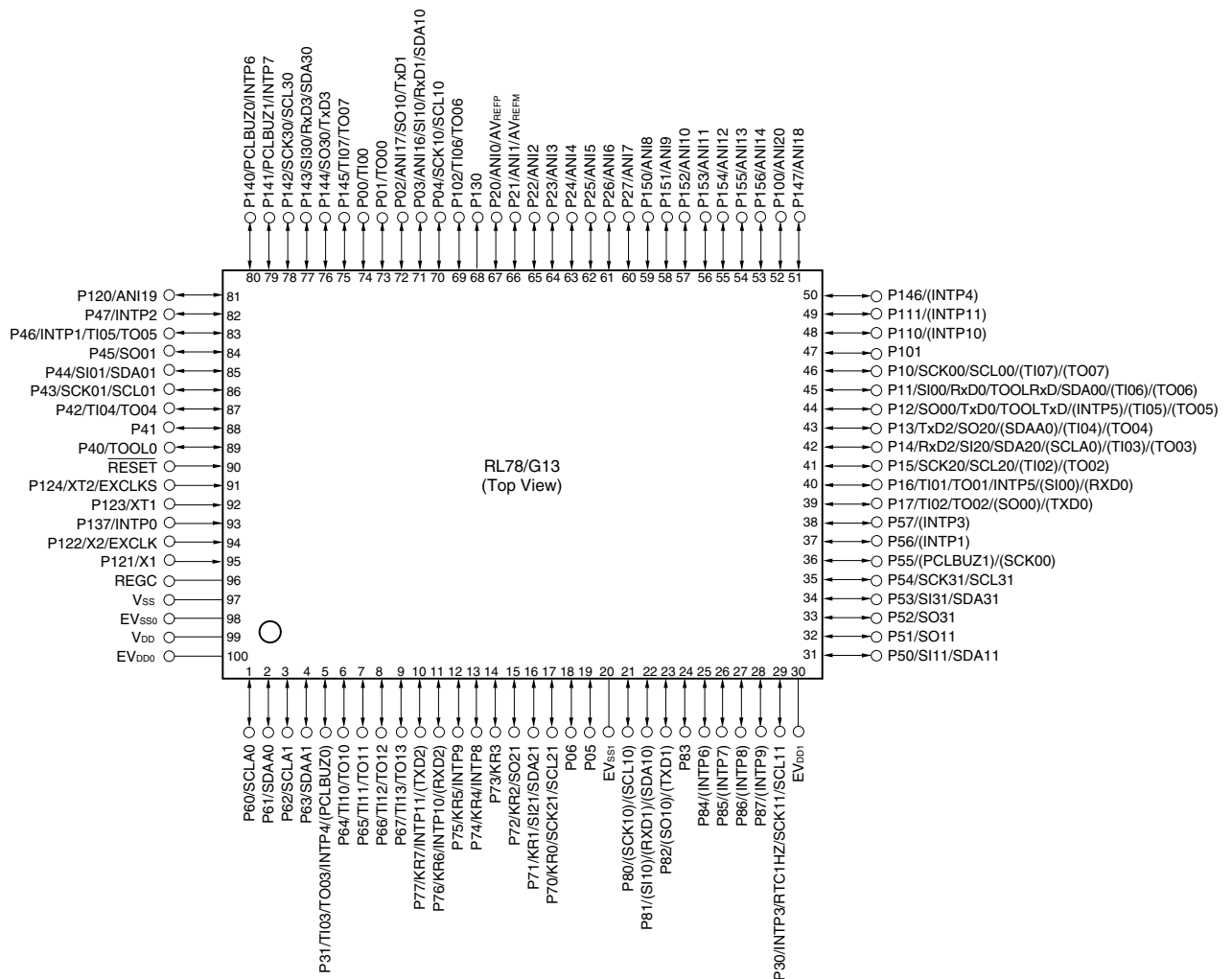


**Caution** Connect the REGC pin to Vss via a capacitor (0.47 to 1  $\mu$ F).

**Remarks 1.** For pin identification, see **1.4 Pin Identification**.

2. Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). Refer to **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)** in the RL78/G13 User's Manual.
3. It is recommended to connect an exposed die pad to  $V_{SS}$ .

- 100-pin plastic LQFP (14 × 20 mm, 0.65 mm pitch)



- Cautions**
1. Make EV<sub>SS0</sub>, EV<sub>SS1</sub> pins the same potential as V<sub>SS</sub> pin.
  2. Make V<sub>DD</sub> pin the potential that is higher than EV<sub>DD0</sub>, EV<sub>DD1</sub> pins (EV<sub>DD0</sub> = EV<sub>DD1</sub>).
  3. Connect the REGC pin to V<sub>SS</sub> via a capacitor (0.47 to 1  $\mu$ F).

- Remarks**
1. For pin identification, see 1.4 Pin Identification.
  2. When using the microcontroller for an application where the noise generated inside the microcontroller must be reduced, it is recommended to supply separate powers to the V<sub>DD</sub>, EV<sub>DD0</sub> and EV<sub>DD1</sub> pins and connect the V<sub>SS</sub>, EV<sub>SS0</sub> and EV<sub>SS1</sub> pins to separate ground lines.
  3. Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). Refer to **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)** in the RL78/G13 User's Manual.

[40-pin, 44-pin, 48-pin, 52-pin, 64-pin products]

**Caution** This outline describes the functions at the time when Peripheral I/O redirection register (PIOR) is set to 00H.

(1/2)

Item		40-pin		44-pin		48-pin		52-pin		64-pin	
		R5F100Ex	R5F101Ex	R5F100Ex	R5F101Ex	R5F100Gx	R5F101Gx	R5F100Jx	R5F101Jx	R5F100Lx	R5F101Lx
Code flash memory (KB)		16 to 192		16 to 512		16 to 512		32 to 512		32 to 512	
Data flash memory (KB)		4 to 8	—	4 to 8	—	4 to 8	—	4 to 8	—	4 to 8	—
RAM (KB)		2 to 16 <sup>Note1</sup>		2 to 32 <sup>Note1</sup>		2 to 32 <sup>Note1</sup>		2 to 32 <sup>Note1</sup>		2 to 32 <sup>Note1</sup>	
Address space		1 MB									
Main system clock	High-speed system clock	X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) HS (High-speed main) mode: 1 to 20 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (High-speed main) mode: 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (Low-speed main) mode: 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V), LV (Low-voltage main) mode: 1 to 4 MHz (V <sub>DD</sub> = 1.6 to 5.5 V)									
	High-speed on-chip oscillator	HS (High-speed main) mode: 1 to 32 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (High-speed main) mode: 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (Low-speed main) mode: 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V), LV (Low-voltage main) mode: 1 to 4 MHz (V <sub>DD</sub> = 1.6 to 5.5 V)									
Subsystem clock		XT1 (crystal) oscillation, external subsystem clock input (EXCLKS) 32.768 kHz									
Low-speed on-chip oscillator		15 kHz (TYP.)									
General-purpose registers		(8-bit register × 8) × 4 banks									
Minimum instruction execution time		0.03125 μs (High-speed on-chip oscillator: f <sub>IH</sub> = 32 MHz operation)									
		0.05 μs (High-speed system clock: f <sub>MX</sub> = 20 MHz operation)									
		30.5 μs (Subsystem clock: f <sub>SUB</sub> = 32.768 kHz operation)									
Instruction set		<ul style="list-style-type: none"><li>• Data transfer (8/16 bits)</li><li>• Adder and subtractor/logical operation (8/16 bits)</li><li>• Multiplication (8 bits × 8 bits)</li><li>• Rotate, barrel shift, and bit manipulation (Set, reset, test, and Boolean operation), etc.</li></ul>									
I/O port	Total	36		40		44		48		58	
	CMOS I/O	28 (N-ch O.D. I/O [V <sub>DD</sub> withstand voltage]: 10)		31 (N-ch O.D. I/O [V <sub>DD</sub> withstand voltage]: 10)		34 (N-ch O.D. I/O [V <sub>DD</sub> withstand voltage]: 11)		38 (N-ch O.D. I/O [V <sub>DD</sub> withstand voltage]: 13)		48 (N-ch O.D. I/O [V <sub>DD</sub> withstand voltage]: 15)	
	CMOS input	5		5		5		5		5	
	CMOS output	—		—		1		1		1	
	N-ch O.D. I/O (withstand voltage: 6 V)	3		4		4		4		4	
Timer	16-bit timer	8 channels									
	Watchdog timer	1 channel									
	Real-time clock (RTC)	1 channel									
	12-bit interval timer (IT)	1 channel									
	Timer output	4 channels (PWM outputs: 3 <sup>Note2</sup> ), 8 channels (PWM outputs: 7 <sup>Note2, Note3</sup> )		5 channels (PWM outputs: 4 <sup>Note2</sup> ), 8 channels (PWM outputs: 7 <sup>Note2</sup> ) <sup>Note3</sup>						8 channels (PWM outputs: 7 <sup>Note2</sup> )	
	RTC output	1 channel • 1 Hz (subsystem clock: f <sub>SUB</sub> = 32.768 kHz)									

**Notes** 1. The flash library uses RAM in self-programming and rewriting of the data flash memory. The target products and start address of the RAM areas used by the flash library are shown below.

R5F100xD, R5F101xD (x = E to G, J, L): Start address FF300H

R5F100xE, R5F101xE (x = E to G, J, L): Start address FEF00H

R5F100xJ, R5F101xJ (x = F, G, J, L): Start address FAF00H

R5F100xL, R5F101xL (x = F, G, J, L): Start address F7F00H

For the RAM areas used by the flash library, see **Self RAM list of Flash Self-Programming Library for RL78 Family (R20UT2944)**.

## 2.1 Absolute Maximum Ratings

Absolute Maximum Ratings (T<sub>A</sub> = 25°C) (1/2)

Parameter	Symbols	Conditions	Ratings	Unit
Supply voltage	V <sub>DD</sub>		-0.5 to +6.5	V
	EV <sub>DD0</sub> , EV <sub>DD1</sub>	EV <sub>DD0</sub> = EV <sub>DD1</sub>	-0.5 to +6.5	V
	EV <sub>SS0</sub> , EV <sub>SS1</sub>	EV <sub>SS0</sub> = EV <sub>SS1</sub>	-0.5 to +0.3	V
REGC pin input voltage	V <sub>IREGC</sub>	REGC	-0.3 to +2.8 and -0.3 to V <sub>DD</sub> + 0.3 <sup>Note 1</sup>	V
Input voltage	V <sub>I1</sub>	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P140 to P147	-0.3 to EV <sub>DD0</sub> + 0.3 and -0.3 to V <sub>DD</sub> + 0.3 <sup>Note 2</sup>	V
	V <sub>I2</sub>	P60 to P63 (N-ch open-drain)	-0.3 to +6.5	V
	V <sub>I3</sub>	P20 to P27, P121 to P124, P137, P150 to P156, EXCLK, EXCLKS, RESET	-0.3 to V <sub>DD</sub> + 0.3 <sup>Note 2</sup>	V
Output voltage	V <sub>O1</sub>	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147	-0.3 to EV <sub>DD0</sub> + 0.3 and -0.3 to V <sub>DD</sub> + 0.3 <sup>Note 2</sup>	V
	V <sub>O2</sub>	P20 to P27, P150 to P156	-0.3 to V <sub>DD</sub> + 0.3 <sup>Note 2</sup>	V
Analog input voltage	V <sub>AI1</sub>	ANI16 to ANI26	-0.3 to EV <sub>DD0</sub> + 0.3 and -0.3 to AV <sub>REF</sub> (+) + 0.3 <sup>Notes 2, 3</sup>	V
	V <sub>AI2</sub>	ANI0 to ANI14	-0.3 to V <sub>DD</sub> + 0.3 and -0.3 to AV <sub>REF</sub> (+) + 0.3 <sup>Notes 2, 3</sup>	V

**Notes 1.** Connect the REGC pin to V<sub>SS</sub> via a capacitor (0.47 to 1 μF). This value regulates the absolute maximum rating of the REGC pin. Do not use this pin with voltage applied to it.

**2.** Must be 6.5 V or lower.

**3.** Do not exceed AV<sub>REF</sub>(+) + 0.3 V in case of A/D conversion target pin.

**Caution** Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

**Remarks 1.** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

**2.** AV<sub>REF</sub>(+) : + side reference voltage of the A/D converter.

**3.** V<sub>SS</sub> : Reference voltage

- Notes**
1. Total current flowing into  $V_{DD}$ ,  $EV_{DD0}$ , and  $EV_{DD1}$ , including the input leakage current flowing when the level of the input pin is fixed to  $V_{DD}$ ,  $EV_{DD0}$ , and  $EV_{DD1}$ , or  $V_{SS}$ ,  $EV_{SS0}$ , and  $EV_{SS1}$ . The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  2. During HALT instruction execution by flash memory.
  3. When high-speed on-chip oscillator and subsystem clock are stopped.
  4. When high-speed system clock and subsystem clock are stopped.
  5. When high-speed on-chip oscillator and high-speed system clock are stopped. When  $RTCLPC = 1$  and setting ultra-low current consumption ( $AMPHS1 = 1$ ). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
  6. Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
  7. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
    - HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$   
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$
    - LS (low-speed main) mode:  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }8\text{ MHz}$
    - LV (low-voltage main) mode:  $1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }4\text{ MHz}$
  8. Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.

- Remarks 1.** f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
2. f<sub>IH</sub>: High-speed on-chip oscillator clock frequency
3. f<sub>SUB</sub>: Subsystem clock frequency (XT1 clock oscillation frequency)
4. Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is T<sub>A</sub> = 25°C

- Notes**
1. Total current flowing into  $V_{DD}$ ,  $EV_{DD0}$ , and  $EV_{DD1}$ , including the input leakage current flowing when the level of the input pin is fixed to  $V_{DD}$ ,  $EV_{DD0}$ , and  $EV_{DD1}$ , or  $V_{SS}$ ,  $EV_{SS0}$ , and  $EV_{SS1}$ . The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  2. During HALT instruction execution by flash memory.
  3. When high-speed on-chip oscillator and subsystem clock are stopped.
  4. When high-speed system clock and subsystem clock are stopped.
  5. When high-speed on-chip oscillator and high-speed system clock are stopped. When  $RTCLPC = 1$  and setting ultra-low current consumption ( $AMPHS1 = 1$ ). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
  6. Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
  7. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
    - HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$  @ 1 MHz to 32 MHz
    - $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$  @ 1 MHz to 16 MHz
    - LS (low-speed main) mode:  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$  @ 1 MHz to 8 MHz
    - LV (low-voltage main) mode:  $1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$  @ 1 MHz to 4 MHz
  8. Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.

- Remarks 1.** f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
2. f<sub>IH</sub>: High-speed on-chip oscillator clock frequency
3. f<sub>SUB</sub>: Subsystem clock frequency (XT1 clock oscillation frequency)
4. Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is T<sub>A</sub> = 25°C

**(10) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I<sup>2</sup>C mode) (2/2)****(T<sub>A</sub> = -40 to +85°C, 1.8 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Data setup time (reception)	t <sub>SU:DAT</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	1/f <sub>MCK</sub> + 135 <sup>Note 3</sup>		1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		kHz
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	1/f <sub>MCK</sub> + 135 <sup>Note 3</sup>		1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		kHz
		4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.8 kΩ	1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		kHz
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.7 kΩ	1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		kHz
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup> , C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5.5 kΩ	1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		kHz
Data hold time (transmission)	t <sub>HD:DAT</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	0	305	0	305	0	305	ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	0	305	0	305	0	305	ns
		4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.8 kΩ	0	355	0	355	0	355	ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.7 kΩ	0	355	0	355	0	355	ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup> , C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5.5 kΩ	0	405	0	405	0	405	ns

**Notes 1.** The value must also be equal to or less than f<sub>MCK</sub>/4.**2.** Use it with EV<sub>DD0</sub> ≥ V<sub>b</sub>.**3.** Set the f<sub>MCK</sub> value to keep the hold time of SCLr = "L" and SCLr = "H".

**Caution** Select the TTL input buffer and the N-ch open drain output (V<sub>DD</sub> tolerance (for the 20- to 52-pin products)/EV<sub>DD</sub> tolerance (for the 64- to 128-pin products)) mode for the SDAr pin and the N-ch open drain output (V<sub>DD</sub> tolerance (for the 20- to 52-pin products)/EV<sub>DD</sub> tolerance (for the 64- to 128-pin products)) mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

**(2) I<sup>2</sup>C fast mode****(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions		HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
				MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCLA0 clock frequency	f <sub>SCL</sub>	Fast mode: f <sub>CLK</sub> ≥ 3.5 MHz	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0	400	0	400	0	400	kHz
			1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0	400	0	400	0	400	kHz
Setup time of restart condition	t <sub>SU:STA</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		0.6		0.6		0.6		μs
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		0.6		0.6		0.6		μs
Hold time <sup>Note 1</sup>	t <sub>HD:STA</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		0.6		0.6		0.6		μs
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		0.6		0.6		0.6		μs
Hold time when SCLA0 = "L"	t <sub>LOW</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		1.3		1.3		1.3		μs
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		1.3		1.3		1.3		μs
Hold time when SCLA0 = "H"	t <sub>HIGH</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		0.6		0.6		0.6		μs
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		0.6		0.6		0.6		μs
Data setup time (reception)	t <sub>SU:DAT</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		100		100		100		μs
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		100		100		100		μs
Data hold time (transmission) <sup>Note 2</sup>	t <sub>HD:DAT</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		0	0.9	0	0.9	0	0.9	μs
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		0	0.9	0	0.9	0	0.9	μs
Setup time of stop condition	t <sub>SU:STO</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		0.6		0.6		0.6		μs
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		0.6		0.6		0.6		μs
Bus-free time	t <sub>BUF</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		1.3		1.3		1.3		μs
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		1.3		1.3		1.3		μs

**Notes** 1. The first clock pulse is generated after this period when the start/restart condition is detected.2. The maximum value (MAX.) of t<sub>HD:DAT</sub> is during normal transfer and a wait state is inserted in the ACK (acknowledge) timing.**Caution** The values in the above table are applied even when bit 2 (PIOR2) in the peripheral I/O redirection register (PIOR) is 1. At this time, the pin characteristics (I<sub>OH1</sub>, I<sub>OL1</sub>, V<sub>OH1</sub>, V<sub>OL1</sub>) must satisfy the values in the redirect destination.**Remark** The maximum value of C<sub>b</sub> (communication line capacitance) and the value of R<sub>b</sub> (communication line pull-up resistor) at that time in each mode are as follows.Fast mode: C<sub>b</sub> = 320 pF, R<sub>b</sub> = 1.1 kΩ

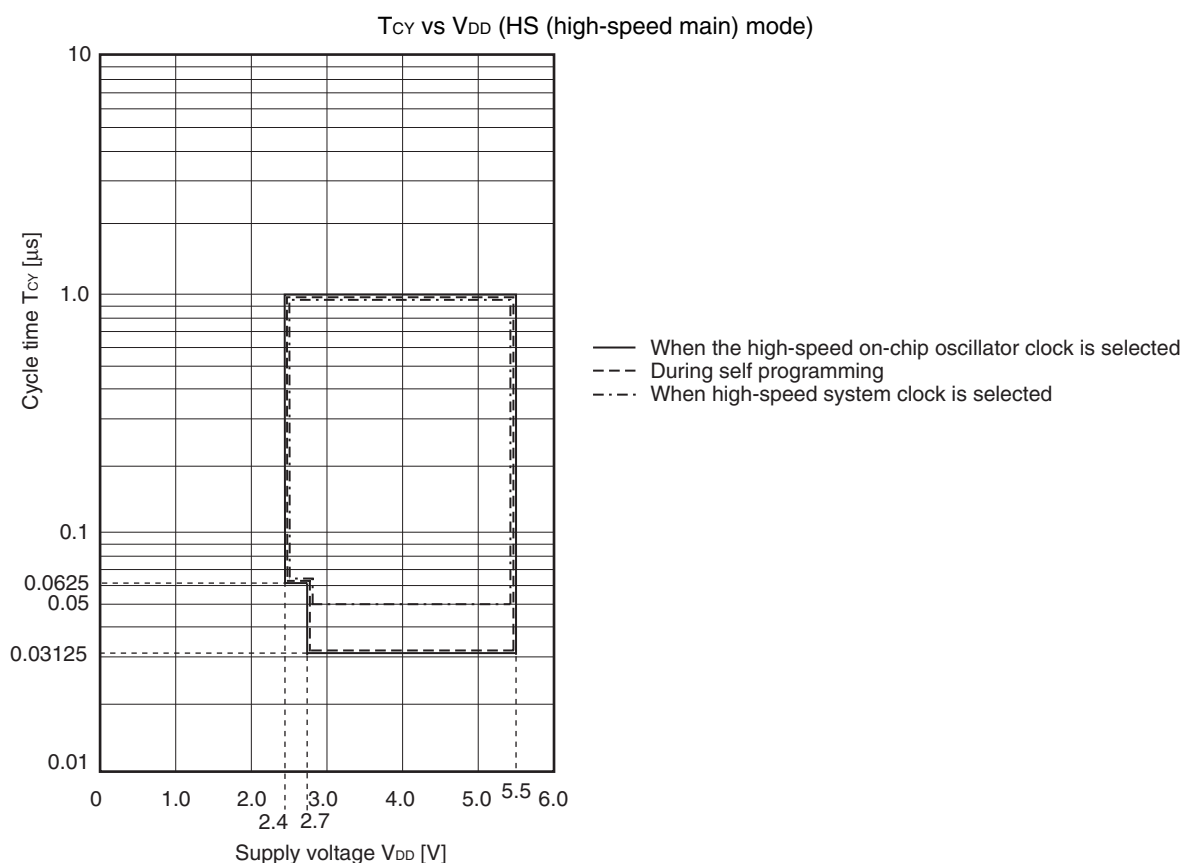
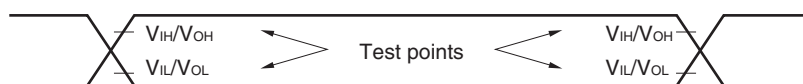
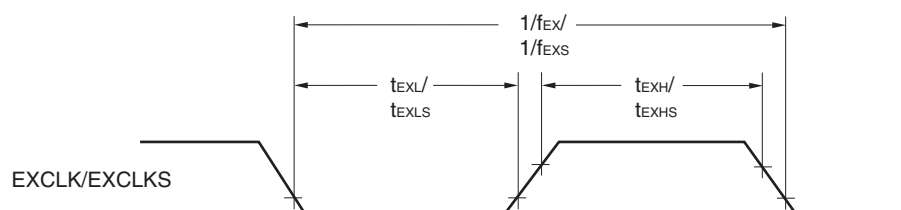
&lt;R&gt;

**( $T_A = -40$  to  $+105^{\circ}\text{C}$ ,  $2.4\text{ V} \leq \text{EV}_{\text{DD0}} = \text{EV}_{\text{DD1}} \leq \text{V}_{\text{DD}} \leq 5.5\text{ V}$ ,  $\text{V}_{\text{SS}} = \text{EV}_{\text{SS0}} = \text{EV}_{\text{SS1}} = 0\text{ V}$ ) (3/5)**

Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input voltage, high	$\text{V}_{\text{IH1}}$	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P140 to P147	Normal input buffer	$0.8\text{EV}_{\text{DD0}}$	$\text{EV}_{\text{DD0}}$	V
	$\text{V}_{\text{IH2}}$	P01, P03, P04, P10, P11, P13 to P17, P43, P44, P53 to P55, P80, P81, P142, P143	TTL input buffer $4.0\text{ V} \leq \text{EV}_{\text{DD0}} \leq 5.5\text{ V}$	2.2	$\text{EV}_{\text{DD0}}$	V
			TTL input buffer $3.3\text{ V} \leq \text{EV}_{\text{DD0}} < 4.0\text{ V}$	2.0	$\text{EV}_{\text{DD0}}$	V
			TTL input buffer $2.4\text{ V} \leq \text{EV}_{\text{DD0}} < 3.3\text{ V}$	1.5	$\text{EV}_{\text{DD0}}$	V
	$\text{V}_{\text{IH3}}$	P20 to P27, P150 to P156	$0.7\text{V}_{\text{DD}}$		$\text{V}_{\text{DD}}$	V
	$\text{V}_{\text{IH4}}$	P60 to P63	$0.7\text{EV}_{\text{DD0}}$		6.0	V
	$\text{V}_{\text{IH5}}$	P121 to P124, P137, EXCLK, EXCLKS, $\overline{\text{RESET}}$	$0.8\text{V}_{\text{DD}}$		$\text{V}_{\text{DD}}$	V
Input voltage, low	$\text{V}_{\text{IL1}}$	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P140 to P147	Normal input buffer	0	$0.2\text{EV}_{\text{DD0}}$	V
	$\text{V}_{\text{IL2}}$	P01, P03, P04, P10, P11, P13 to P17, P43, P44, P53 to P55, P80, P81, P142, P143	TTL input buffer $4.0\text{ V} \leq \text{EV}_{\text{DD0}} \leq 5.5\text{ V}$	0	0.8	V
			TTL input buffer $3.3\text{ V} \leq \text{EV}_{\text{DD0}} < 4.0\text{ V}$	0	0.5	V
			TTL input buffer $2.4\text{ V} \leq \text{EV}_{\text{DD0}} < 3.3\text{ V}$	0	0.32	V
	$\text{V}_{\text{IL3}}$	P20 to P27, P150 to P156	0		$0.3\text{V}_{\text{DD}}$	V
	$\text{V}_{\text{IL4}}$	P60 to P63	0		$0.3\text{EV}_{\text{DD0}}$	V
	$\text{V}_{\text{IL5}}$	P121 to P124, P137, EXCLK, EXCLKS, $\overline{\text{RESET}}$	0		$0.2\text{V}_{\text{DD}}$	V

**Caution** The maximum value of  $\text{V}_{\text{IH}}$  of pins P00, P02 to P04, P10 to P15, P17, P43 to P45, P50, P52 to P55, P71, P74, P80 to P82, P96, and P142 to P144 is  $\text{EV}_{\text{DD0}}$ , even in the N-ch open-drain mode.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

**Minimum Instruction Execution Time during Main System Clock Operation****AC Timing Test Points****External System Clock Timing**

**(2) During communication at same potential (CSI mode) (master mode, SCKp... internal clock output)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq \text{EV}_{\text{DD}0} = \text{EV}_{\text{DD}1} \leq \text{V}_{\text{DD}} \leq 5.5\text{ V}$ ,  $\text{V}_{\text{SS}} = \text{EV}_{\text{SS}0} = \text{EV}_{\text{SS}1} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
SCKp cycle time	$t_{\text{KCY}1}$	$t_{\text{KCY}1} \geq 4/f_{\text{CLK}}$			
		$2.7\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$	250		ns
		$2.4\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$	500		ns
SCKp high-/low-level width	$t_{\text{KH}1},$ $t_{\text{KL}1}$	$4.0\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$	$t_{\text{KCY}1}/2 - 24$		ns
		$2.7\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$	$t_{\text{KCY}1}/2 - 36$		ns
		$2.4\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$	$t_{\text{KCY}1}/2 - 76$		ns
Slp setup time (to SCKp $\uparrow$ ) <sup>Note 1</sup>	$t_{\text{SIK}1}$	$4.0\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$	66		ns
		$2.7\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$	66		ns
		$2.4\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$	113		ns
Slp hold time (from SCKp $\uparrow$ ) <sup>Note 2</sup>	$t_{\text{KSI}1}$		38		ns
Delay time from SCKp $\downarrow$ to SOp output <sup>Note 3</sup>	$t_{\text{KSO}1}$	$C = 30\text{ pF}$ <sup>Note 4</sup>		50	ns

- Notes**
1. When  $\text{DAPmn} = 0$  and  $\text{CKPmn} = 0$ , or  $\text{DAPmn} = 1$  and  $\text{CKPmn} = 1$ . The Slp setup time becomes “to SCKp $\downarrow$ ” when  $\text{DAPmn} = 0$  and  $\text{CKPmn} = 1$ , or  $\text{DAPmn} = 1$  and  $\text{CKPmn} = 0$ .
  2. When  $\text{DAPmn} = 0$  and  $\text{CKPmn} = 0$ , or  $\text{DAPmn} = 1$  and  $\text{CKPmn} = 1$ . The Slp hold time becomes “from SCKp $\downarrow$ ” when  $\text{DAPmn} = 0$  and  $\text{CKPmn} = 1$ , or  $\text{DAPmn} = 1$  and  $\text{CKPmn} = 0$ .
  3. When  $\text{DAPmn} = 0$  and  $\text{CKPmn} = 0$ , or  $\text{DAPmn} = 1$  and  $\text{CKPmn} = 1$ . The delay time to SOp output becomes “from SCKp $\uparrow$ ” when  $\text{DAPmn} = 0$  and  $\text{CKPmn} = 1$ , or  $\text{DAPmn} = 1$  and  $\text{CKPmn} = 0$ .
  4. C is the load capacitance of the SCKp and SOp output lines.

**Caution** Select the normal input buffer for the Slp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

- Remarks**
1. p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3),  
g: PIM and POM numbers (g = 0, 1, 4, 5, 8, 14)
  2.  $f_{\text{MCK}}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

(4) During communication at same potential (simplified I<sup>2</sup>C mode)(T<sub>A</sub> =  $-40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq \text{EV}_{\text{DD}0} = \text{EV}_{\text{DD}1} \leq \text{V}_{\text{DD}} \leq 5.5\text{ V}$ ,  $\text{V}_{\text{SS}} = \text{EV}_{\text{SS}0} = \text{EV}_{\text{SS}1} = 0\text{ V}$ )

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
SCLr clock frequency	f <sub>SCL</sub>	$2.7\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$		400 <sup>Note1</sup>	kHz
		$2.4\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$		100 <sup>Note1</sup>	
Hold time when SCLr = "L"	t <sub>LOW</sub>	$2.7\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	1200		ns
		$2.4\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$	4600		ns
Hold time when SCLr = "H"	t <sub>HIGH</sub>	$2.7\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	1200		ns
		$2.4\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$	4600		ns
Data setup time (reception)	t <sub>SU:DAT</sub>	$2.7\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	$1/\text{f}_{\text{MCK}} + 220$ <sup>Note2</sup>		ns
		$2.4\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$	$1/\text{f}_{\text{MCK}} + 580$ <sup>Note2</sup>		ns
Data hold time (transmission)	t <sub>HD:DAT</sub>	$2.7\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	0	770	ns
		$2.4\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$	0	1420	ns

**Notes** 1. The value must also be equal to or less than  $\text{f}_{\text{MCK}}/4$ .2. Set the  $\text{f}_{\text{MCK}}$  value to keep the hold time of SCLr = "L" and SCLr = "H".

**Caution** Select the normal input buffer and the N-ch open drain output ( $\text{V}_{\text{DD}}$  tolerance (for the 20- to 52-pin products)/ $\text{EV}_{\text{DD}}$  tolerance (for the 64- to 100-pin products)) mode for the SDAr pin and the normal output mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register h (POMh).

(Remarks are listed on the next page.)

**(5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode) (1/2)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq EV_{DD0} = EV_{DD1} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = EV_{SS0} = EV_{SS1} = 0\text{ V}$ )**

Parameter	Symbol	Conditions		HS (high-speed main) Mode		Unit
				MIN.	MAX.	
Transfer rate		Reception	$4.0\text{ V} \leq EV_{DD0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$		$f_{MCK}/12$ <sup>Note 1</sup>	bps
			Theoretical value of the maximum transfer rate $f_{CLK} = 32\text{ MHz}$ , $f_{MCK} = f_{CLK}$		2.6	Mbps
			$2.7\text{ V} \leq EV_{DD0} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$		$f_{MCK}/12$ <sup>Note 1</sup>	bps
			Theoretical value of the maximum transfer rate $f_{CLK} = 32\text{ MHz}$ , $f_{MCK} = f_{CLK}$		2.6	Mbps
			$2.4\text{ V} \leq EV_{DD0} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$		$f_{MCK}/12$ <sup>Notes 1,2</sup>	bps
			Theoretical value of the maximum transfer rate $f_{CLK} = 32\text{ MHz}$ , $f_{MCK} = f_{CLK}$		2.6	Mbps

**Notes 1.** Transfer rate in the SNOOZE mode is 4800 bps only.

- 2.** The following conditions are required for low voltage interface when  $EV_{DD0} < V_{DD}$ .  
 $2.4\text{ V} \leq EV_{DD0} < 2.7\text{ V}$  : MAX. 1.3 Mbps

**Caution** Select the TTL input buffer for the RxDq pin and the N-ch open drain output ( $V_{DD}$  tolerance (for the 20- to 52-pin products)/ $EV_{DD}$  tolerance (for the 64- to 100-pin products)) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.

**Remarks 1.**  $V_b[V]$ : Communication line voltage

- 2.** q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 8, 14)

- 3.**  $f_{MCK}$ : Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

- 4.** UART2 cannot communicate at different potential when bit 1 (PIOR1) of peripheral I/O redirection register (PIOR) is 1.

## 3.8 Flash Memory Programming Characteristics

**( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
CPU/peripheral hardware clock frequency	f <sub>CLK</sub>	$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	1		32	MHz
Number of code flash rewrites <small>Notes 1,2,3</small>	C <sub>enwr</sub>	Retained for 20 years $T_A = 85^\circ\text{C}$ <small>Note 4</small>	1,000			Times
Number of data flash rewrites <small>Notes 1,2,3</small>		Retained for 1 years $T_A = 25^\circ\text{C}$		1,000,000		
		Retained for 5 years $T_A = 85^\circ\text{C}$ <small>Note 4</small>	100,000			
		Retained for 20 years $T_A = 85^\circ\text{C}$ <small>Note 4</small>	10,000			

- Notes**
- 1 erase + 1 write after the erase is regarded as 1 rewrite. The retaining years are until next rewrite after the rewrite.
  2. When using flash memory programmer and Renesas Electronics self programming library.
  3. These are the characteristics of the flash memory and the results obtained from reliability testing by Renesas Electronics Corporation.
  4. This temperature is the average value at which data are retained.

## 3.9 Dedicated Flash Memory Programmer Communication (UART)

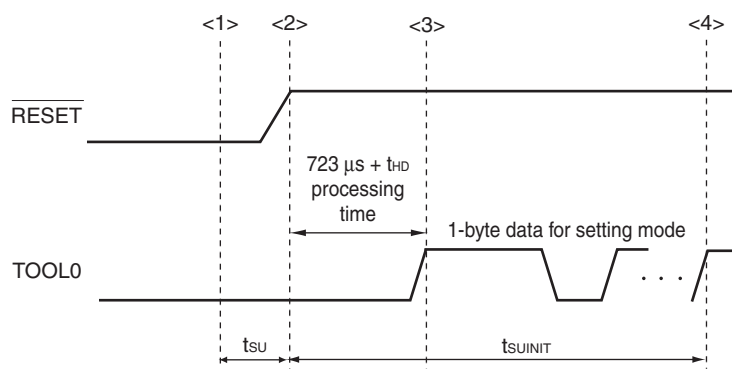
**( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD0} = V_{DD1} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = V_{SS0} = V_{SS1} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate		During serial programming	115,200		1,000,000	bps

## 3.10 Timing of Entry to Flash Memory Programming Modes

(T<sub>A</sub> =  $-40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq \text{EV}_{\text{DD0}} = \text{EV}_{\text{DD1}} \leq \text{V}_{\text{DD}} \leq 5.5\text{ V}$ ,  $\text{V}_{\text{SS}} = \text{EV}_{\text{SS0}} = \text{EV}_{\text{SS1}} = 0\text{ V}$ )

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Time to complete the communication for the initial setting after the external reset is released	$t_{\text{SUNIT}}$	POR and LVD reset must be released before the external reset is released.			100	ms
Time to release the external reset after the TOOL0 pin is set to the low level	$t_{\text{SU}}$	POR and LVD reset must be released before the external reset is released.	10			$\mu\text{s}$
Time to hold the TOOL0 pin at the low level after the external reset is released (excluding the processing time of the firmware to control the flash memory)	$t_{\text{HD}}$	POR and LVD reset must be released before the external reset is released.	1			ms



&lt;1&gt; The low level is input to the TOOL0 pin.

&lt;2&gt; The external reset is released (POR and LVD reset must be released before the external reset is released.).

&lt;3&gt; The TOOL0 pin is set to the high level.

&lt;4&gt; Setting of the flash memory programming mode by UART reception and complete the baud rate setting.

**Remark**  $t_{\text{SUNIT}}$ : Communication for the initial setting must be completed within 100 ms after the external reset is released during this period.

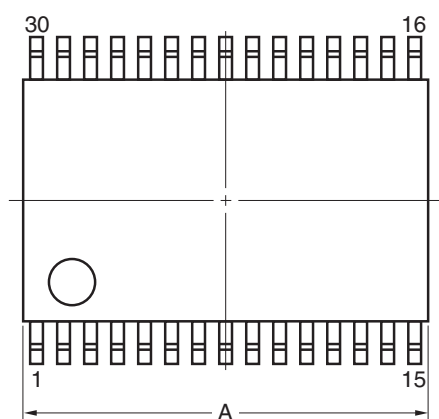
$t_{\text{SU}}$ : Time to release the external reset after the TOOL0 pin is set to the low level

$t_{\text{HD}}$ : Time to hold the TOOL0 pin at the low level after the external reset is released (excluding the processing time of the firmware to control the flash memory)

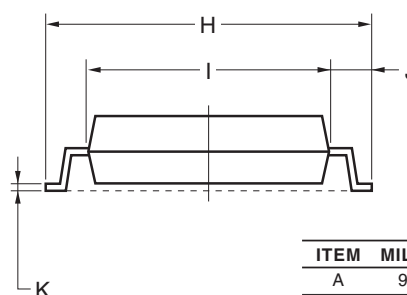
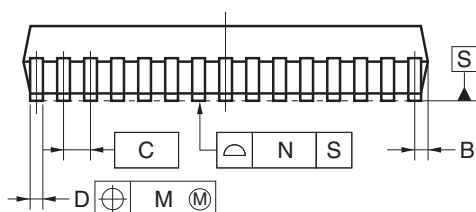
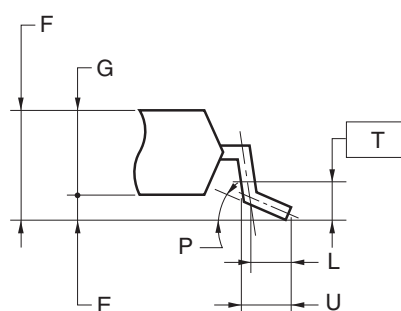
## 4.4 30-pin Products

R5F100AAASP, R5F100ACASP, R5F100ADASP, R5F100AEASP, R5F100AFASP, R5F100AGASP  
 R5F101AAASP, R5F101ACASP, R5F101ADASP, R5F101AEASP, R5F101AFASP, R5F101AGASP  
 R5F100AADSP, R5F100ACDSP, R5F100ADDSP, R5F100AEDSP, R5F100AFDSP, R5F100AGDSP  
 R5F101AADSP, R5F101ACDSP, R5F101ADDSP, R5F101AEDSP, R5F101AFDSP, R5F101AGDSP  
 R5F100AAGSP, R5F100ACGSP, R5F100ADGSP, R5F100AEGSP, R5F100AFGSP, R5F100AGGSP

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LSSOP30-0300-0.65	PLSP0030JB-B	S30MC-65-5A4-3	0.18



detail of lead end

**NOTE**

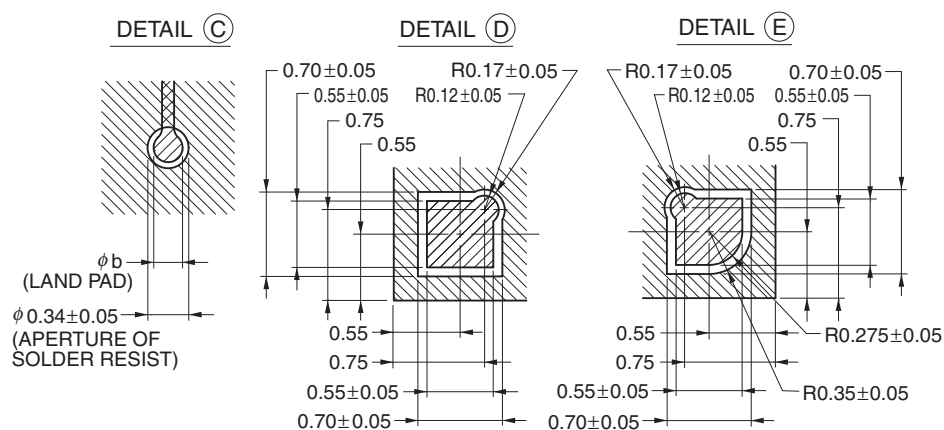
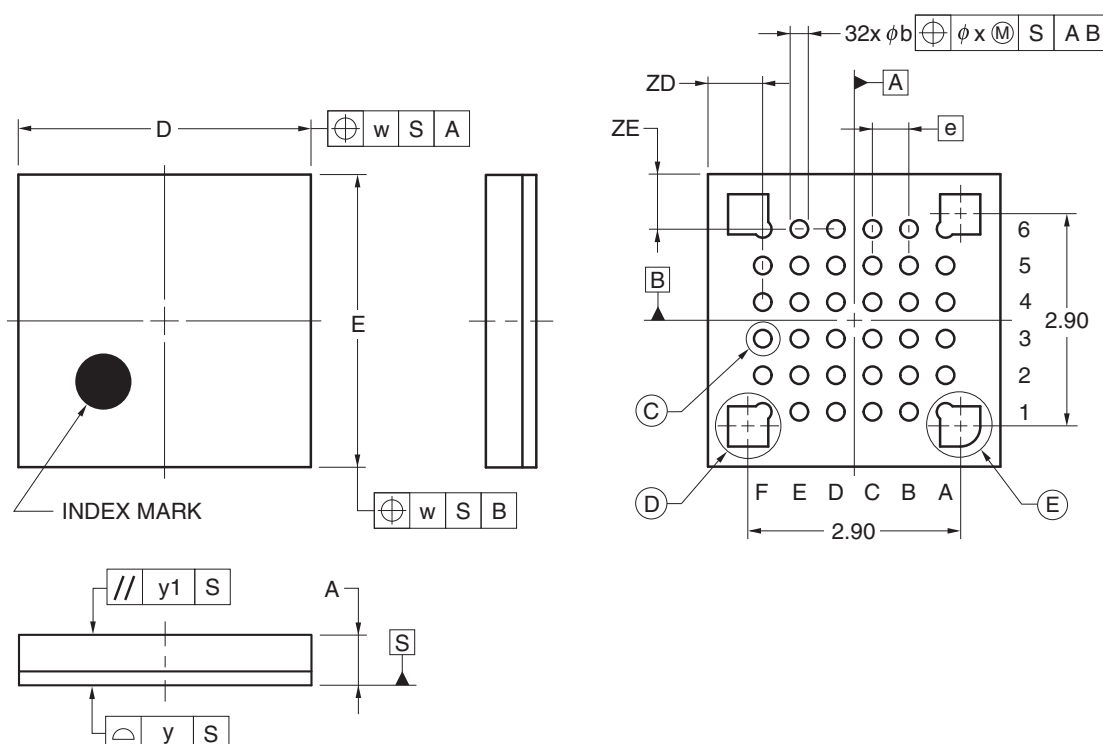
Each lead centerline is located within 0.13 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS
A	9.85±0.15
B	0.45 MAX.
C	0.65 (T.P.)
D	0.24 <sup>+0.08</sup> <sub>-0.07</sub>
E	0.1±0.05
F	1.3±0.1
G	1.2
H	8.1±0.2
I	6.1±0.2
J	1.0±0.2
K	0.17±0.03
L	0.5
M	0.13
N	0.10
P	3° <sup>+5°</sup> <sub>-3°</sub>
T	0.25
U	0.6±0.15

## 4.6 36-pin Products

R5F100CAALA, R5F100CCALA, R5F100CDALA, R5F100CEALA, R5F100CFALA, R5F100CGALA  
 R5F101CAALA, R5F101CCALA, R5F101CDALA, R5F101CEALA, R5F101CFALA, R5F101CGALA  
 R5F100CAGLA, R5F100CCGLA, R5F100CDGLA, R5F100CEGLA, R5F100CFGLA, R5F100CGGLA

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-WFLGA36-4x4-0.50	PWLG0036KA-A	P36FC-50-AA4-2	0.023



(UNIT:mm)

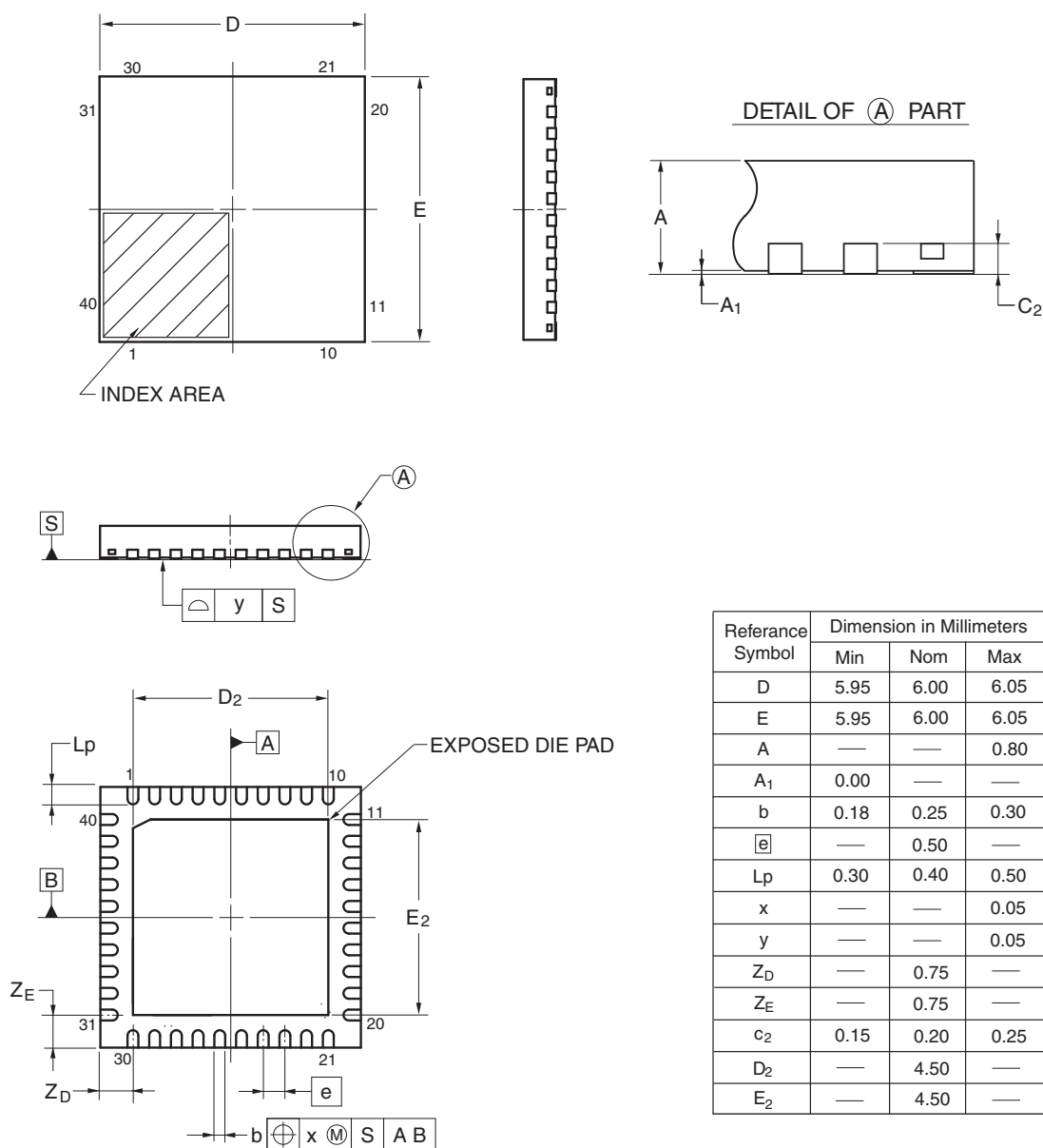
ITEM	DIMENSIONS
D	4.00±0.10
E	4.00±0.10
w	0.20
e	0.50
A	0.69±0.07
b	0.24±0.05
x	0.05
y	0.08
y1	0.20
ZD	0.75
ZE	0.75

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## 4.7 40-pin Products

R5F100EAANA, R5F100ECANA, R5F100EDANA, R5F100EEANA, R5F100EFANA, R5F100EGANA, R5F100EHANA  
 R5F101EAANA, R5F101ECANA, R5F101EDANA, R5F101EEANA, R5F101EFANA, R5F101EGANA, R5F101EHANA  
 R5F100EADNA, R5F100ECDNA, R5F100EDDNA, R5F100EEDNA, R5F100EFDNA, R5F100EGDNA,  
 R5F100EHDNA  
 R5F101EADNA, R5F101ECDNA, R5F101EDDNA, R5F101EEDNA, R5F101EFDNA, R5F101EGDNA,  
 R5F101EHDNA  
 R5F100EAGNA, R5F100ECGNA, R5F100EDGNA, R5F100EEGNA, R5F100EFGNA, R5F100EGGNA,  
 R5F100EHGNA

JEITA Package code	RENESAS code	Previous code	MASS (TYP.) [g]
P-HWQFN40-6x6-0.50	PWQN0040KC-A	P40K8-50-4B4-5	0.09



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